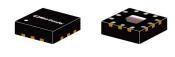
# **SPDT RF Switch**

JSW2-33HDR-75+

75 $\Omega$  5 to 3000 MHz High Power 3W

# **The Big Deal**

- High IP3, +70 dBm typ.
- High Power P0.1dB greater than 3W
- Low Insertion Loss, 0.33 dB at 1 GHz



CASE STYLE: MT1818

## **Product Overview**

JSW2-33HDR-75+ is a high-power reflective SPDT RF switch, with reflective short on output ports in the OFF state. Made using a Silicon-on-Insulator process, it provides very high IP3 (+70 dBm typ.). This switch also has a built-in CMOS driver and negative voltage generator, all packaged in a tiny 2x2mm package, enabling it to operate over wideband and fit into tight spaces.

# **Key Features**

Feature	Advantages
High IIP3: +70 dBm typ.	Outstanding third order intercept perfomance makes this part ideal for use with high modulation signals such as digital CATV, QAM and other dense waveforms
Wideband operation 5-3000 MHz	Enables a single component to be used in a vast array of applications from VHF up to 3 GHz.
Low Loss, 0.33 dB at 1 GHz & high input power, 3W	Low loss and high power capability enables a single switch to be used for a variety of applications, saving inventory.
Built in negative voltage generator	Operates with single positive supply voltage; no need for DC blocking capacitors, unless external DC is present at the RF ports.
Built-in CMOS driver	No need for external driver, saving PCB space and cost.
Tiny MCLP package 2 x 2mm, 12-lead	Provides low inductance, repeatable transitions, and excellent thermal contact to PCB.

Reflective RF Switch with internal driver. Single Supply Voltage, +2.3V to +4.8V, High Power 3W

## **Product Features**

- High IP3, +70 dBm typ. at 150 MHz
- High Power, P0.1dB 3W
- High Isolation, 42 dB typ. at 1 GHz
- Low insertion loss, 0.33 dB typ. at 1 GHz
- Low current consumption, 37 μA typ.



#### +RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

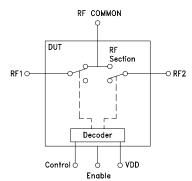
## **Typical Applications**

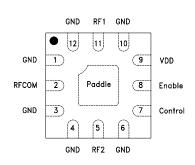
- CATV systems
- SATCOM system
- Automated Test Stations

### **General Description**

JSW2-33HDR-75+ is a high power (35 dBm) reflective SPDT switch with integral CMOS driver, operates with single positive supply voltage while consuming,  $37\mu$ A typical. JSW is a reflective short on output port in OFF state. It has been designed for very wideband operation of 5-3000 MHz. It is packaged in a tiny 2mm x 2mm x 0.55mm package and is rated MSL1 and class 1B for ESD (HBM)

# Simplified Schematic and Pad Description





Function	Pad Number	Description
RF COM	2	RF Common/ SUM Port, (see Fig. 2)
RF1	11	RF Out #1/In Port #1, (see Fig. 2)
RF2	5	RF Out #1/In Port #2, (see Fig. 2)
Control	7	CMOS Control IN
VDD	9	Supply Voltage
Enable	8	Shutdown mode enabled by connecting to logic low
Ground	1,3,4,6,10,12	Ground Externally

## RF Electrical Specifications<sup>(1)</sup>, 5 - 3000 MHz, $T_{AMB}$ =25°C, $V_{DD}$ = +2.3 to 4.8V

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units	
Frequency Range		5		3000	MHz	
	5 to 1000		0.33	0.48	dB	
Insertion Loss <sup>(2)</sup>	1000 to 1500		0.44	0.58		
(ON STATE)	1500 to 2000		0.51	0.64		
	2000 to 3000		0.53	0.64		
Input IP3 (V <sub>DD</sub> =3V)	150		+70			
	1800		+70		dBm	
0.1dB Input Compression <sup>(4)</sup>	20 to 3000		35.0		dBm	
	5 to 1000	40	42		dB	
Isolation between Common port and RF1/RF2 Ports	1000 to 1500	35	38			
Isolation between Common port and RF1/RF2 Ports	1500 to 2000	32	35			
	2000 to 3000	28	31			
	5 to 1000	40	45			
looletian between DE1 and DE2 nexts(3)	1000 to 1500	35	41		dB	
Isolation between RF1 and RF2 ports <sup>(3)</sup>	1500 to 2000	32	37		ав	
	2000 to 3000	28	32			
	5 to 1000		19			
Detrum Loca (ON STATE) all porte	1000 to 1500		16		dB	
Return Loss (ON STATE), all ports	1500 to 2000		16		ФВ	
	2000 to 3000		17			

### **DC Operating Electrical Specifications**

Parameter	Min.	Тур.	Max.	Units
VDD, Supply Voltage	2.3		4.8	V
Supply Current		37		μΑ
Control Enable Voltage Low	0		0.4	V
Control Enable Voltage High <sup>(5)</sup>	1.65		2.7	V
Control Current		1		μΑ
Shutdown mode - Supply Current		7		μΑ

#### Notes:

- 1. Tested on Mini-Circuit's test board TB-723-N+ (see Characterization Test Circuit, Fig.1).

- 2. Insertion loss values include test board loss.
  3. Enable voltage "HI", either RF1 or RF2 are ON.
  4. Do not exceed RF input power as shown in Absolute Maximum Rating table.
  5. If V<sub>DO</sub> < 2.7, then Max Control Voltage High=V<sub>DO</sub>

## **Switching Specifications**

Parameter	Min.	Тур.	Max.	Units
Rise/Fall Time (10 to 90% or 90 to 10% RF)	_	0.5 (Rise Time) 0.7 (Fall Time)	_	μSec
Switching Time, 50% CTRL to 90/10% RF	_	1.9 (ON Time) 1.1 (OFF Time)	_	μSec
Video Feedthrough, (control 0 to 1.65V, freq.=10 KHz)	_	3.0	_	mV <sub>p.p</sub>

#### Absolute Maximum Ratings(6)

Parameter	Ratings	
Operating Temperature	-40°C to +85°C	
Storage Temperature	-55°C to 125°C	
V <sub>DD</sub> , Supply Voltage	5.0V	
Voltage Control	-0.2V Min. V <sub>DD</sub> Max.	
RF input power	5 Watt <sup>7</sup>	

<sup>6.</sup> Operation of this device above any of these conditions may cause permanent damage.

Truth Table (State of control and enable voltage selects the desired switch state)

State of:		RF Common to		
Control Voltage	Enable Voltage	RF1	RF2	
High	High	ON	OFF	
Low	High	OFF	ON	
Low/High	Low	Shutdown		

ON- low insertion loss state OFF- Isolation State

#### **Characterization Test Circuit**

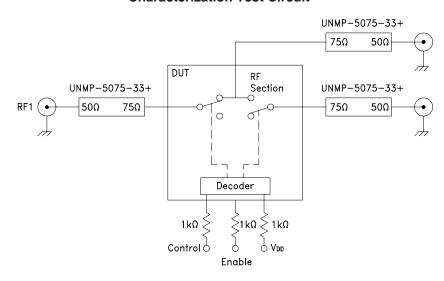


Figure 1: Block Diagram Of Test Circuit Used For Characterization. (DUT soldered on Mini-Circuit's TB-723-N+)

#### **Test Equipment:**

For Insertion loss, Isolation, Return loss:

Agilent's N5230A Network Analyzer , E3631A power supply. Mini-Circuits Matching Pad UNMP-5075-33+ For Switching Time and Video Feed through

Agilent's AG54832B HP81110A pulse generator, HPE3631A Network Analyzer, E3631A power supply. Agilent's N90A Spectrum Analyzer, E8257D Generator U200A

For Compression:

R&S Network Analyzer ZVA24, E3631A power supply.

#### Conditions:

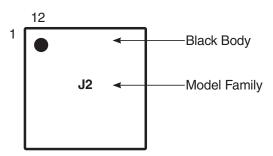
 $V_{DD}$ = +2.3 and +4.8V, Control= 0 and 1.65V.

For Insertion loss, isolation and return loss: Pin=0 dBm

For Input IP3: Pin=+20 dBm / tone. Tones: 154.6 MHz & 165.0 MHz / 1747.5 MHz & 1842.5 MHz For Switching time: RF frequency: DC at 0 dBm, Control Frequency: 500 KHz and 0 and +1.65V.

<sup>7.</sup> Derate linearly to 2.5W at 85°C.

# **Product Marking**



# **Recommended Application Circuit**

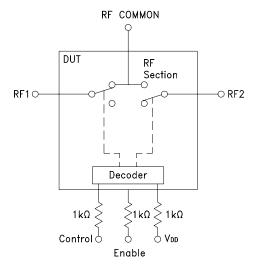


Fig. 2: Evaluation board includes case, connectors and components soldered to PCB.